Energy stored in static electric field :

We suppose three charge in free region with E=0, the total work of these charges is : *o*.

$$W_E = W_1 + W_2 + W_3$$
$$W_E = 0 + Q_2 V_{2,1} + (Q_3 V_{3,1} + Q_3 V_{3,2})$$

Where W_E is the energy stored in the electric field of the charge distribution.



Now if the three charge were brought into place in revers order, the total work would be

$$W_E = W_3 + W_2 + W_1$$
$$W_E = 0 + Q_2 V_{2,3} + (Q_1 V_{1,2} + Q_1 V_{1,3})$$

When the tow result above added, we obtained the twice of stored energy.

$$2W_E = Q_1(V_{1,2} + V_{1,3}) + Q_2(V_{2,1} + V_{2,3}) + Q_3(V_{3,1} + V_{3,2})$$

The term $Q_1(V_{1,3} + V_{1,2})$ was the work done aganist the electric fields
of Q_2 and Q_3 so $(V_{1,2} + V_{1,3}) = V_1$ the potential at position 1 then :
$$2W_E = Q_1V_1 + Q_2V_2 + Q_3V_3$$

 $W_E = \frac{1}{2}\sum_{m=1}^n Q_mV_m$ For a region containing n point charge
 $W_E = \frac{1}{2}\int \rho V \, dv$ For a region with a charge density ρ $(\frac{C}{m^3})$
 $W_E = \frac{1}{2}\int D.E \, dv$ $W_E = \frac{1}{2}\int \varepsilon E^2 \, dv$ $W_E = \frac{1}{2}\int \frac{D^2}{\varepsilon} \, dv$ Other forms
In an electric circuit the energy stored in the field of a capacitor is
given by :

$$W_E = \frac{1}{2}QV = \frac{1}{2}CV^2$$

1. What energy stored in system of two point charges $Q_1 = 3 nC$; $Q_1 = -3 nC$ separated by d=0.2 m?

$$2W_E = Q_1 V_1 + Q_2 V_2$$

$$2W_E = Q_1 \left(\frac{Q_2}{4\pi\varepsilon_0 d}\right) + Q_2 \left(\frac{Q_1}{4\pi\varepsilon_0 d}\right)$$

$$2W_E = \frac{2Q_1 Q_2}{4\pi\varepsilon_0 d} = \frac{(-3 \times 10^{-9}) \times (3 \times 10^{-9})}{4\pi (\frac{10^{-9}}{36\pi})(0.2)} = -405 \, nJ$$

2. What energy stored of four point charges 4 nC seperated by d=1 m?

$$2W_E = Q_1 V_1 + Q_2 V_2 + Q_3 V_3 + Q_4 V_4$$

$$2W_E = 4Q_1 V_1$$

$$2W_E = 4Q_1 \left(\frac{Q}{4\pi\varepsilon_0}\right) \left(\frac{1}{1} + \frac{1}{1} + \frac{1}{\sqrt{2}}\right)$$

$$W_E = \left(\frac{8 \times 10^{-9} \times 4 \times 10^{-9}}{4\pi(\frac{10^{-9}}{36\pi})}\right) \left(\frac{1}{1} + \frac{1}{1} + \frac{1}{\sqrt{2}}\right)$$

$$W_E = 780 \ nJ$$



3. A parallel plate capacitor , for which $C = \frac{\varepsilon A}{d}$ has a constant voltageV applied acrosse the plates. Find the stored energy in the electric field .

$$E = (V/d)_{a_n}$$
 between the plates and E=0 elsewhere. v_{\pm}^{\pm}
 $W_E = \frac{1}{2} \int \varepsilon E^2 dv$

$$W_E = \frac{\varepsilon}{2} \left(\frac{V}{d}\right)^2 \int dv$$
$$W_E = \frac{\varepsilon}{2} \frac{AV^2}{d}$$
$$W_E = \frac{1}{2} CV^2$$

Current, Current density and Conductors

Electric current is the rate of transport of electric charge past a specified point or across specific surface..

$$I = \frac{Q}{t} \frac{C}{sec} = Ampere$$

Charges in Motion

Consider the force on positively charged particle in an electric field in vacuum, as shown in figure. This force F = +QE is unopposed and results in constant acceleration. Thus the charge moves in the direction of E with a velosity U that increases as long as the particle in the E field.

 $U = \mu E$ The most elementary expression of Ohm's law



 μ mobility has unit m²/V.s and U drift velosity.

In terms of the basic properties of the right-cylindrical currentcarrying metallic ohmic conductor, where the charge-carriers are electrons, this expression can be rewritten as:

$$U = \frac{m\sigma\Delta V}{\rho efl}$$

- U is again the drift velocity of the electrons, in $m \cdot s^{-1}$
- *m* is the molecular mass of the metal, in kg

- σ is the electric conductivity of the medium at the temperature considered, in S/m.
- ΔV is the voltage applied across the conductor, in V
- ρ is the density (mass per unit volume) of the conductor, in kg·m⁻³
- *e is the elementary charge, in C*

Convection current density J

If we have particle with density charge ρ in a volume v as in figure. As this charge configuration passes a surface S it constitutes a convection current with density.

$$J = \rho U \ (\frac{A}{m^2})$$

Conduction current density J

The conduction current density that occurs in the presence of an electric field within a conductor of fixed cross section.

From
$$J = \rho U$$
 and $U = \mu E$

$$J = \rho \mu E$$

 $J = \sigma E$

 $\sigma = \rho \mu S/m$ is the conductivity of the material.

Conductivity σ :







Gas or liquid	Conductor	Semiconductor
$\sigma = \rho^- \mu^- + \rho^+ \mu^+$	$\sigma = \rho_e \mu_e$	$\sigma = \rho_e \mu_e + \rho_h \mu_h$

Current I :

If the current density J crosses a surface S, as in figure , the current I obtained by the integration the dot product of J and ds.

$$dI = J.\,ds$$
 $I = \int_{S} J.\,ds$

1. What electric field intensity and current density correspond to drift velosity of $6 \times 10^{-4} m/s$ in a silver conductor ? for silver

$$\sigma = 61.7 \frac{MS}{m} \text{ and } \mu = 5.6 \times 10^{-3} \frac{m^2}{V.s}$$
$$E = \frac{U}{\mu} = \frac{6 \times 10^{-4}}{5.6 \times 10^{-3}} = 1.07 \times 10^{-1} \ V/m$$
$$J = \sigma E = 61.7 \times 10^6 \times 1.07 \times 10^{-1} = 6.61 \times 10^6 \ A/m^2$$

2. Find the current in the circular wire as in figure if the current density is $J=15(1-e^{-1000})a_z$ (A/m²). The radius of the wire is 2mm.

$$dI = J. ds$$

$$dI = 15(1 - e^{-1000})a_z \cdot rdr \, d\emptyset \, a_z$$

$$I = \int_0^{2\pi} \int_0^{0.002} 15(1 - e^{-1000}) \, rdr \, d\emptyset$$

$$I = 1.33 \times 10^{-4} \, A = 0.133 \, A$$



Lecture 9

3. Find the current crossing the portion of the x=0 plane defined by $-\frac{\pi}{4} \le y \le \frac{\pi}{4} \quad , -0.01 \le z \le 0.01 \text{ m if } J = 100 \cos 2y \ a_x \ A/m^2 ?$ $I = \int J \cdot ds$ $I = \int_{-0.01}^{0.01} \int_{-\frac{\pi}{4}}^{\frac{\pi}{4}} 100 \cos 2y \ a_x \cdot dy \ dz \ a_x = 2 \ A$

Resistance R

If a conductor of uniform crosse sectional area A and length L as in figure has a voltage difference V between its ends then $E_{L} = E_{L} + E_{L}$

$$E = \frac{V}{L}$$
 and $J = \frac{\sigma V}{L}$

Assuming that the current is uniformly distributed over the area A. The total current is then

$$I = J A = \frac{\sigma A V}{L}$$

Since Ohm's law states that V=IR, the resistance is

$$R = \frac{L}{\sigma A} \quad \Omega$$

For nonuniform current distributions the resistance is given by :

$$R = \frac{V}{\int J \cdot ds} = \frac{V}{\int \sigma E \cdot ds}$$
$$R = \frac{\int E \cdot dl}{\int \sigma E \cdot ds}$$



Continuity of current

$$\oint J \cdot ds = I = \frac{-dQ}{dt} = \frac{-\partial}{\partial t} \int \rho \, dv$$
$$\frac{\oint J \cdot ds}{\Delta v} = \frac{-\partial}{\partial t} \int \frac{\rho \, dv}{\Delta v}$$
$$\overrightarrow{\nabla} \cdot \overrightarrow{J} = \frac{-\partial\rho}{\partial t}$$
$$\overrightarrow{\nabla} \cdot \overrightarrow{J} = 0$$
 Kirchhoff Current Law

Conductor dielectric boundary conditions.

Under static condition all the net charge outer surface of conductor and both E and D are therefore zero within the conductor. Because the electric fiel dis conservative



$$\oint E \cdot dl = 0$$

$$\oint_{1}^{2} E \cdot dl + \oint_{2}^{3} E \cdot dl + \oint_{3}^{4} E \cdot dl + \oint_{4}^{1} E \cdot dl$$

$$\oint_{1}^{2} E \cdot dl = 0 \qquad E_{t} = D_{t} = 0$$

$$\oint D \cdot ds = Q$$

$$\int_{top} D \cdot ds + \int_{bottom} D \cdot ds + \int_{slide} D \cdot ds$$

$$= \int_{A} \rho_{s} \cdot ds$$

$$D_{t} = \rho_{s} \qquad E_{t} = \frac{\rho_{s}}{\varepsilon}$$

Electromagnatic

Lecture 9

Exemple : Find the resistance between the inner and the outer curved surfaces of the block as in figure where the material is silver for which $\sigma = 6.17 \times 10^7 S/m$?



$$J = \frac{k}{r} a_r \quad and \quad E = \frac{k}{\sigma r} a_r$$

$$R = \frac{\int_{0.2}^{0.3} \frac{k}{\sigma r} a_r \cdot dr a_r}{\int_0^{0.05} \int_0^{0.0873} \frac{k}{r} a_r \cdot r \, d\emptyset \, dz \, a_r}$$

$$R = \frac{\ln 15}{\sigma(0.05)(0.0873)} = 1.01 \times 10^{-5} \Omega = 10.1 \, \mu\Omega$$